

# RF Power LDMOS Transistors

## N-Channel Enhancement-Mode Lateral MOSFETs

These high ruggedness devices are designed for use in high VSWR military, aerospace and defense, industrial (including laser and plasma exciters), broadcast (analog and digital), and radio/land mobile applications. They are unmatched input and output designs allowing wide frequency range utilization, between 1.8 and 600 MHz.

- Typical Performance:  $V_{DD} = 50$  Vdc,  $I_{DQ} = 100$  mA

| Signal Type                              | $P_{out}$<br>(W) | f<br>(MHz) | $G_{ps}$<br>(dB) | $\eta_D$<br>(%) | IRL<br>(dB) |
|------------------------------------------|------------------|------------|------------------|-----------------|-------------|
| Pulse (100 $\mu$ sec,<br>20% Duty Cycle) | 600 Peak         | 230        | 25.0             | 74.6            | -18         |
| CW                                       | 600 Avg.         | 230        | 24.6             | 75.2            | -17         |

- Capable of Handling a Load Mismatch of 65:1 VSWR @ 50 Vdc, 230 MHz, at all Phase Angles, Designed for Enhanced Ruggedness
  - 600 W Pulse Peak Power, 20% Duty Cycle, 100  $\mu$ sec

### Features

- Unmatched Input and Output Allowing Wide Frequency Range Utilization
- Device can be used Single-Ended or in a Push-Pull Configuration
- Qualified Up to a Maximum of 50 V<sub>DD</sub> Operation
- Characterized from 30 V to 50 V for Extended Power Range
- Suitable for Linear Application with Appropriate Biasing
- Integrated ESD Protection with Greater Negative Gate-Source Voltage Range for Improved Class C Operation
- Characterized with Series Equivalent Large-Signal Impedance Parameters
- In Tape and Reel. R5 Suffix = 50 Units, 56 mm Tape Width, 13-inch Reel.

Table 1. Maximum Ratings

| Rating                                                                   | Symbol    | Value        | Unit      |
|--------------------------------------------------------------------------|-----------|--------------|-----------|
| Drain-Source Voltage                                                     | $V_{DSS}$ | -0.5, +133   | Vdc       |
| Gate-Source Voltage                                                      | $V_{GS}$  | -6.0, +10    | Vdc       |
| Storage Temperature Range                                                | $T_{stg}$ | -65 to +150  | °C        |
| Case Operating Temperature                                               | $T_C$     | 150          | °C        |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$<br>Derate above 25°C | $P_D$     | 1667<br>8.33 | W<br>W/°C |
| Operating Junction Temperature (1,2)                                     | $T_J$     | 225          | °C        |

Table 2. Thermal Characteristics

| Characteristic                                                                                | Symbol          | Value (2,3) | Unit |
|-----------------------------------------------------------------------------------------------|-----------------|-------------|------|
| Thermal Resistance, Junction to Case                                                          |                 |             |      |
| Case Temperature 68°C, 600 W Peak, 100 $\mu$ sec Pulse Width, 20% Duty Cycle, 100 mA, 230 MHz | $Z_{\theta JC}$ | 0.022       | °C/W |
| Case Temperature 60°C, 600 W CW, 100 mA, 230 MHz                                              | $R_{\theta JC}$ | 0.12        |      |

- Continuous use at maximum temperature will affect MTTF.
- MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.
- Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.

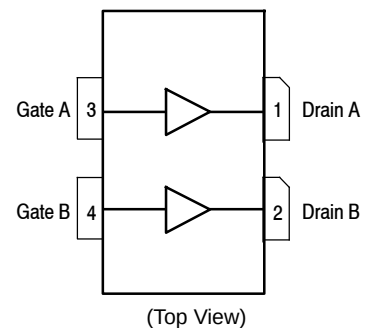
## MMRF1308HR5 MMRF1308HSR5

1.8-600 MHz, 600 W CW, 50 V  
BROADBAND  
RF POWER MOSFETs

NI-1230H-4S  
MMRF1308HR5

NI-1230S-4S  
MMRF1308HSR5

PARTS ARE PUSH-PULL



Note: The backside of the package is the source terminal for the transistors.

Figure 1. Pin Connections

**Table 3. ESD Protection Characteristics**

| Test Methodology                      | Class |
|---------------------------------------|-------|
| Human Body Model (per JESD22-A114)    | 2     |
| Machine Model (per EIA/JESD22-A115)   | B     |
| Charge Device Model (per JESD22-C101) | IV    |

**Table 4. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**Off Characteristics <sup>(1)</sup>**

|                                                                                                    |               |     |   |    |                 |
|----------------------------------------------------------------------------------------------------|---------------|-----|---|----|-----------------|
| Gate-Source Leakage Current<br>( $V_{GS} = 5\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )               | $I_{GSS}$     | —   | — | 1  | $\mu\text{Adc}$ |
| Drain-Source Breakdown Voltage<br>( $V_{GS} = 0\text{ Vdc}$ , $I_D = 100\text{ mA}$ )              | $V_{(BR)DSS}$ | 133 | — | —  | Vdc             |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 50\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ )  | $I_{DSS}$     | —   | — | 10 | $\mu\text{Adc}$ |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 100\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$     | —   | — | 20 | $\mu\text{Adc}$ |

**On Characteristics**

|                                                                                                               |              |     |      |     |     |
|---------------------------------------------------------------------------------------------------------------|--------------|-----|------|-----|-----|
| Gate Threshold Voltage <sup>(1)</sup><br>( $V_{DS} = 10\text{ Vdc}$ , $I_D = 960\text{ }\mu\text{Adc}$ )      | $V_{GS(th)}$ | 1.7 | 2.2  | 2.7 | Vdc |
| Gate Quiescent Voltage<br>( $V_{DD} = 50\text{ Vdc}$ , $I_D = 100\text{ mAdc}$ , Measured in Functional Test) | $V_{GS(Q)}$  | 2.0 | 2.5  | 3.0 | Vdc |
| Drain-Source On-Voltage <sup>(1)</sup><br>( $V_{GS} = 10\text{ Vdc}$ , $I_D = 2\text{ Adc}$ )                 | $V_{DS(on)}$ | —   | 0.26 | —   | Vdc |

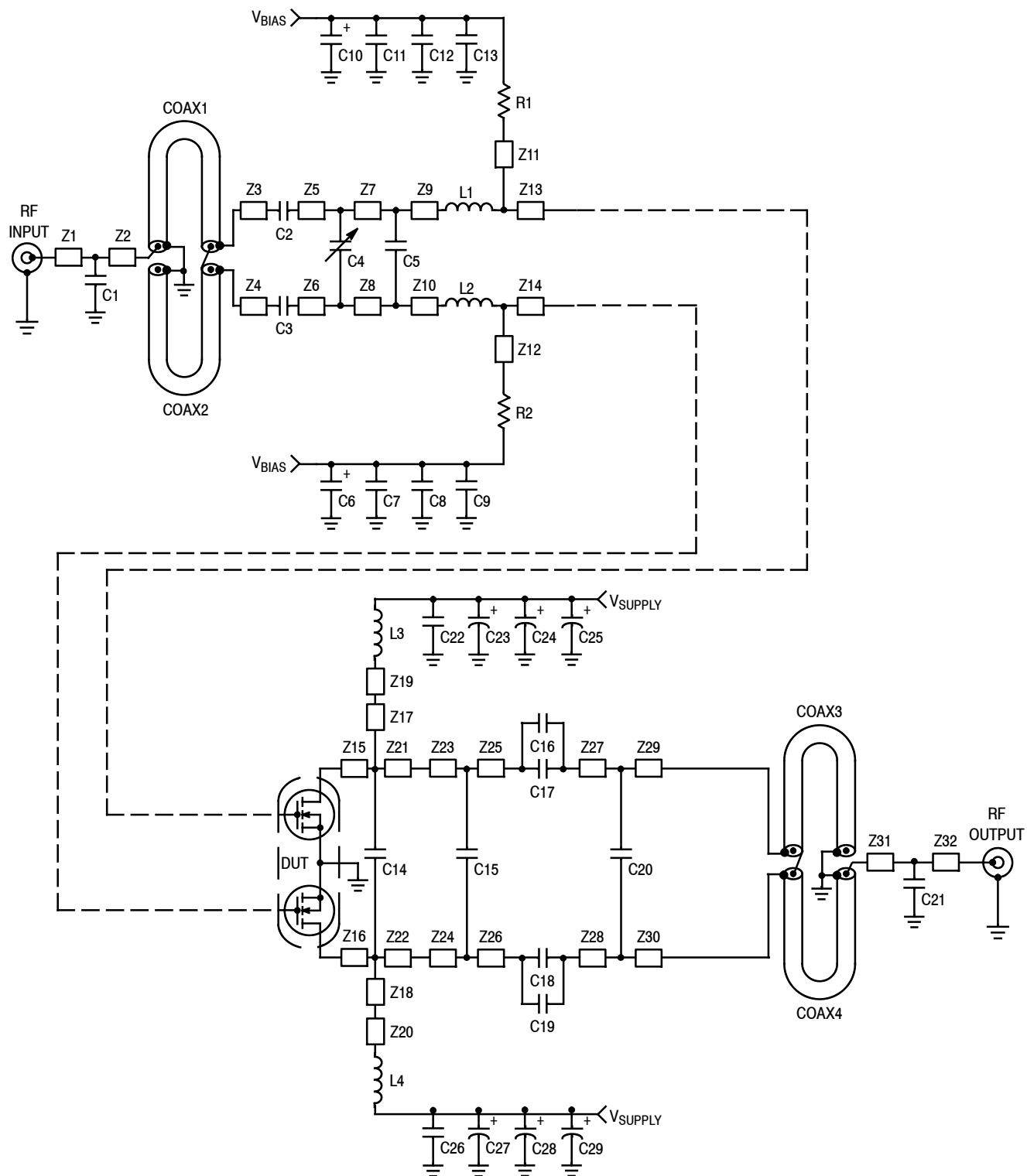
**Dynamic Characteristics <sup>(1)</sup>**

|                                                                                                                       |           |   |      |   |    |
|-----------------------------------------------------------------------------------------------------------------------|-----------|---|------|---|----|
| Reverse Transfer Capacitance<br>( $V_{DS} = 50\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ ) | $C_{rss}$ | — | 1.60 | — | pF |
| Output Capacitance<br>( $V_{DS} = 50\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ )           | $C_{oss}$ | — | 129  | — | pF |
| Input Capacitance<br>( $V_{DS} = 50\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz)            | $C_{iss}$ | — | 342  | — | pF |

**Functional Tests** (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 50\text{ Vdc}$ ,  $I_{DQ} = 100\text{ mA}$ ,  $P_{out} = 600\text{ W Peak}$  (120 W Avg.),  $f = 230\text{ MHz}$ , 100  $\mu\text{sec}$  Pulse Width, 20% Duty Cycle

|                   |          |      |      |      |    |
|-------------------|----------|------|------|------|----|
| Power Gain        | $G_{ps}$ | 23.5 | 25.0 | 26.5 | dB |
| Drain Efficiency  | $\eta_D$ | 73.5 | 74.6 | —    | %  |
| Input Return Loss | IRL      | —    | -18  | -12  | dB |

1. Each side of device measured separately.



|         |                            |
|---------|----------------------------|
| Z1      | 0.192" x 0.082" Microstrip |
| Z2      | 0.175" x 0.082" Microstrip |
| Z3, Z4  | 0.170" x 0.100" Microstrip |
| Z5, Z6  | 0.116" x 0.285" Microstrip |
| Z7, Z8  | 0.116" x 0.285" Microstrip |
| Z9, Z10 | 0.108" x 0.285" Microstrip |

|            |                            |
|------------|----------------------------|
| Z11*, Z12* | 0.872" x 0.058" Microstrip |
| Z13, Z14   | 0.412" x 0.726" Microstrip |
| Z15, Z16   | 0.371" x 0.507" Microstrip |
| Z17*, Z18* | 0.466" x 0.363" Microstrip |
| Z19*, Z20* | 1.187" x 0.154" Microstrip |
| Z21, Z22   | 0.104" x 0.507" Microstrip |

|          |                            |
|----------|----------------------------|
| Z23, Z24 | 1.251" x 0.300" Microstrip |
| Z25, Z26 | 0.127" x 0.300" Microstrip |
| Z27, Z28 | 0.058" x 0.300" Microstrip |
| Z29, Z30 | 0.058" x 0.300" Microstrip |
| Z31      | 0.186" x 0.082" Microstrip |
| Z32      | 0.179" x 0.082" Microstrip |

\* Line length includes microstrip bends

Figure 2. MMRF1308HR5(HSR5) Test Circuit Schematic - Pulse

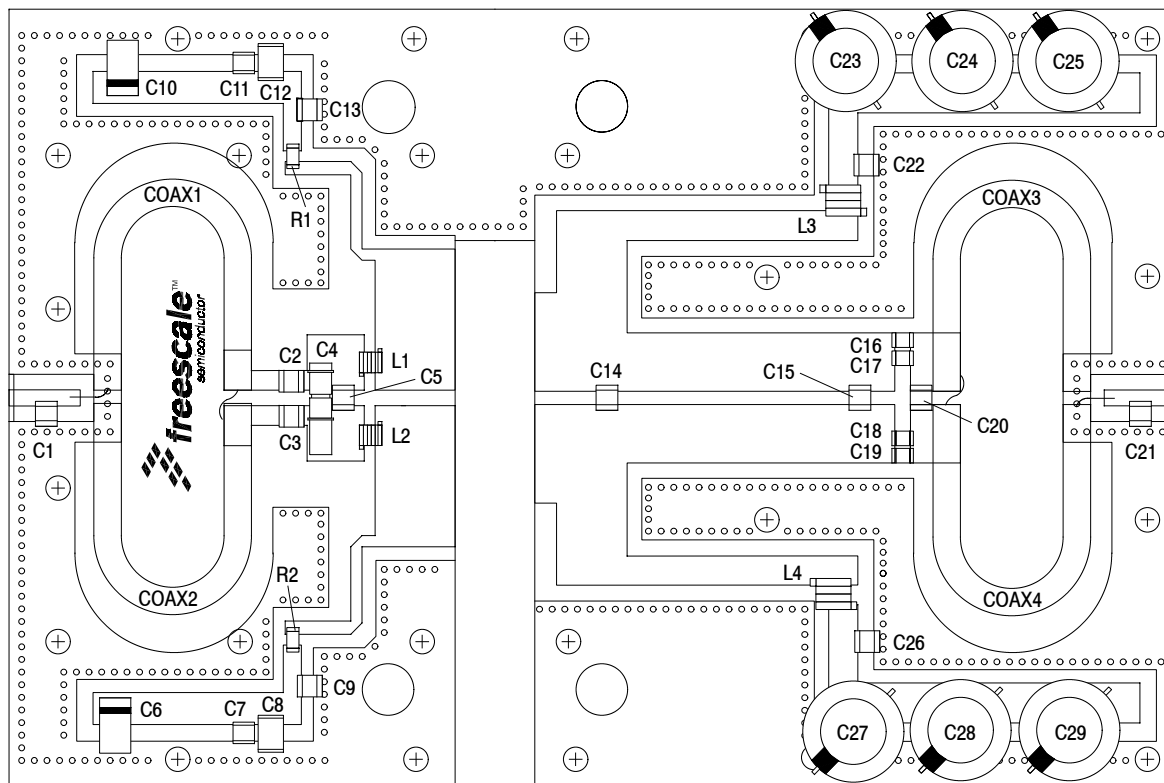
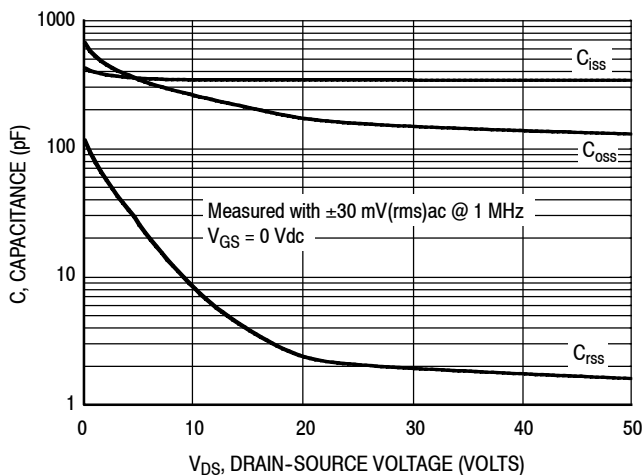


Figure 3. MMRF1308HR5(HSR5) Test Circuit Component Layout - Pulse

Table 5. MMRF1308HR5(HSR5) Test Circuit Component Designations and Values - Pulse

| Part                         | Description                                     | Part Number          | Manufacturer |
|------------------------------|-------------------------------------------------|----------------------|--------------|
| C1                           | 12 pF Chip Capacitor                            | ATC100B120JT500XT    | ATC          |
| C2, C3                       | 27 pF Chip Capacitors                           | ATC100B270JT500XT    | ATC          |
| C4                           | 0.8–8.0 pF Variable Capacitor, Gigatrim         | 27291SL              | Johanson     |
| C5                           | 33 pF Chip Capacitor                            | ATC100B330JT500XT    | ATC          |
| C6, C10                      | 22 $\mu$ F, 35 V Tantalum Capacitors            | T491X226K035AT       | Kemet        |
| C7, C11                      | 0.1 $\mu$ F Chip Capacitors                     | CDR33BX104AKYS       | AVX          |
| C8, C12                      | 220 nF Chip Capacitors                          | C1812C224K5RACTU     | Kemet        |
| C9, C13, C22, C26            | 1000 pF Chip Capacitors                         | ATC100B102JT50XT     | ATC          |
| C14                          | 36 pF Chip Capacitor                            | ATC100B360JT500XT    | ATC          |
| C15                          | 51 pF Chip Capacitor                            | ATC100B510GT500XT    | ATC          |
| C16, C17, C18, C19           | 240 pF Chip Capacitors                          | ATC100B241JT200XT    | ATC          |
| C20                          | 39 pF Chip Capacitor                            | ATC100B390JT500XT    | ATC          |
| C21                          | 10 pF Chip Capacitor                            | ATC100B100JT500XT    | ATC          |
| C23, C24, C25, C27, C28, C29 | 470 $\mu$ F, 63 V Electrolytic Capacitors       | MCGPR63V477M13X26-RH | Multicomp    |
| Coax1, 2, 3, 4               | 25 $\Omega$ Semi Rigid Coax, 2.2" Shield Length | UT-141C-25           | Micro Coax   |
| L1, L2                       | 5 nH Inductors                                  | A02TKLC              | Coilcraft    |
| L3, L4                       | 6.6 nH Inductors                                | GA3093-ALC           | Coilcraft    |
| R1, R2                       | 10 $\Omega$ Chip Resistors                      | CRCW120610R0JNEA     | Vishay       |
| PCB                          | 0.030", $\epsilon_r = 2.55$                     | AD255A               | Arlon        |

## TYPICAL CHARACTERISTICS



Note: Each side of device measured separately.

Figure 4. Capacitance versus Drain-Source Voltage

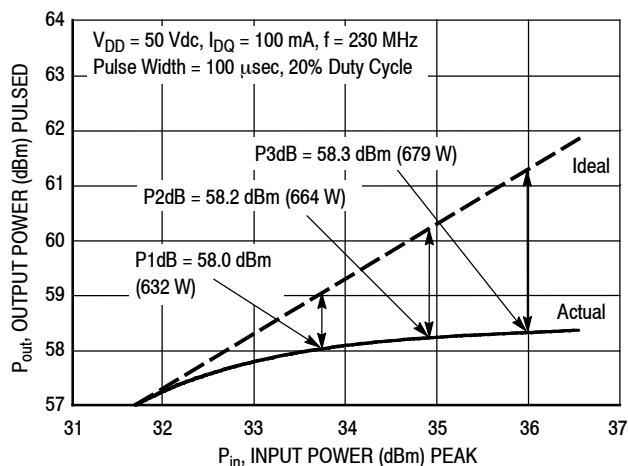


Figure 5. Output Power versus Input Power

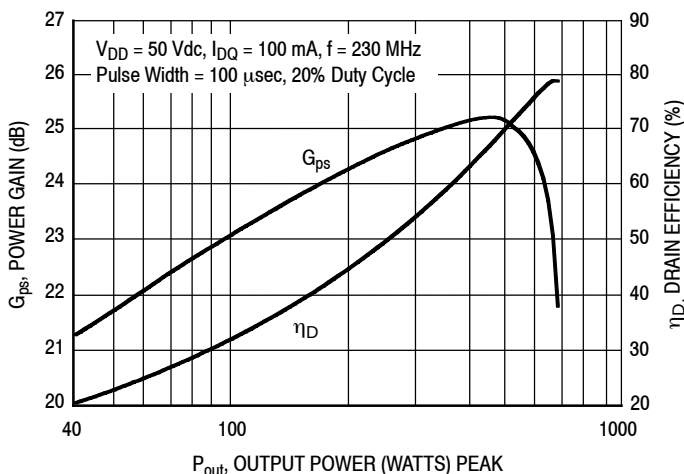


Figure 6. Power Gain and Drain Efficiency versus Output Power

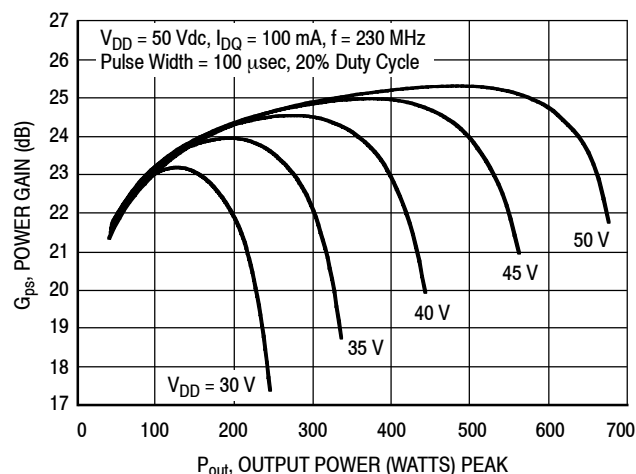


Figure 7. Power Gain versus Output Power

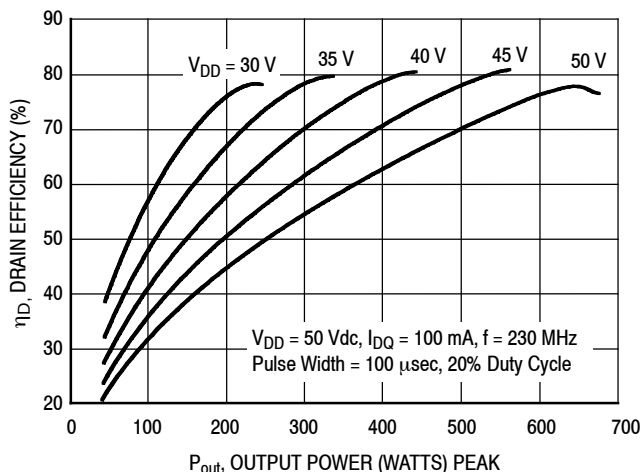


Figure 8. Drain Efficiency versus Output Power

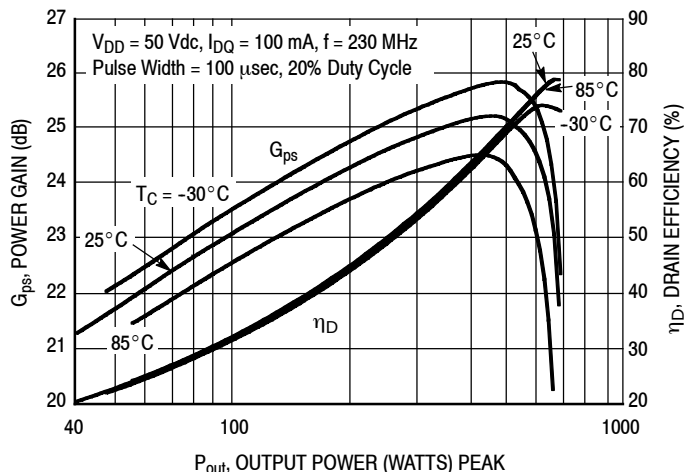
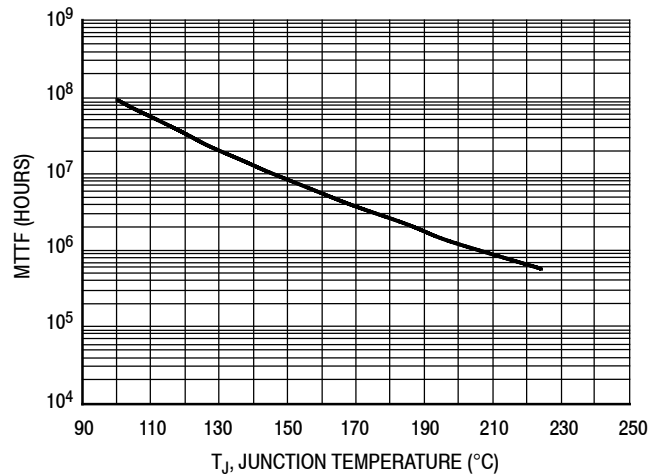


Figure 9. Power Gain and Drain Efficiency versus Output Power

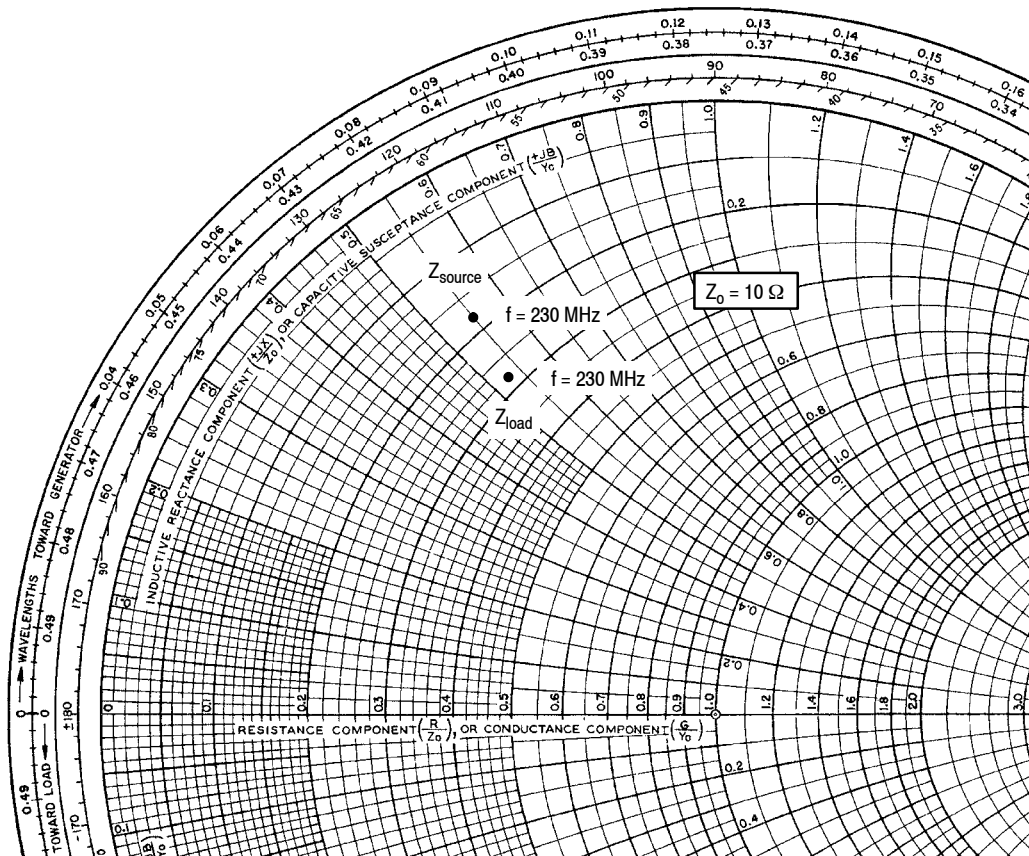
## TYPICAL CHARACTERISTICS



This above graph displays calculated MTTF in hours when the device is operated at  $V_{DD} = 50$  Vdc,  $P_{out} = 600$  W Avg., and  $\eta_D = 75.2\%$ .

MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.

**Figure 10. MTTF versus Junction Temperature — CW**



$V_{DD} = 50 \text{ Vdc}$ ,  $I_{DQ} = 100 \text{ mA}$ ,  $P_{out} = 600 \text{ W Peak}$

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 230      | $1.78 + j5.45$           | $2.75 + j5.30$         |

$Z_{source}$  = Test circuit impedance as measured from gate to gate, balanced configuration.

$Z_{load}$  = Test circuit impedance as measured from drain to drain, balanced configuration.

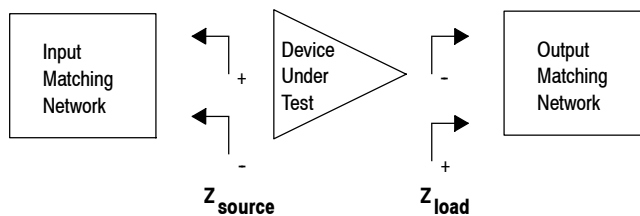
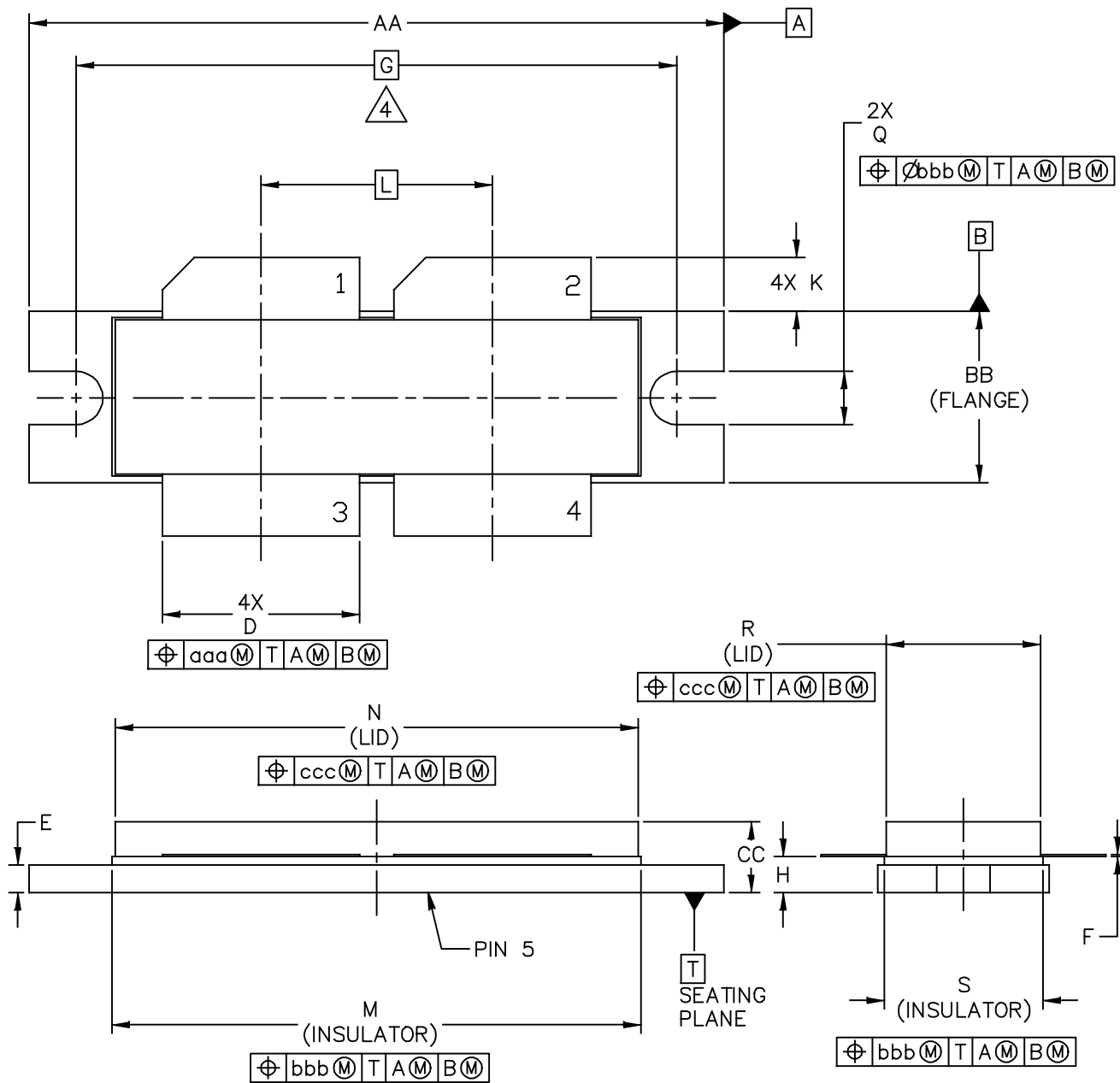


Figure 11. Series Equivalent Source and Load Impedance

# PACKAGE DIMENSIONS



|                                                         |                                      |                            |
|---------------------------------------------------------|--------------------------------------|----------------------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. | MECHANICAL OUTLINE                   | PRINT VERSION NOT TO SCALE |
| TITLE:<br><br>NI-1230-4H                                | DOCUMENT NO: 98ASB16977C      REV: F |                            |
|                                                         | STANDARD: NON-JEDEC                  |                            |
|                                                         | 28 FEB 2013                          |                            |

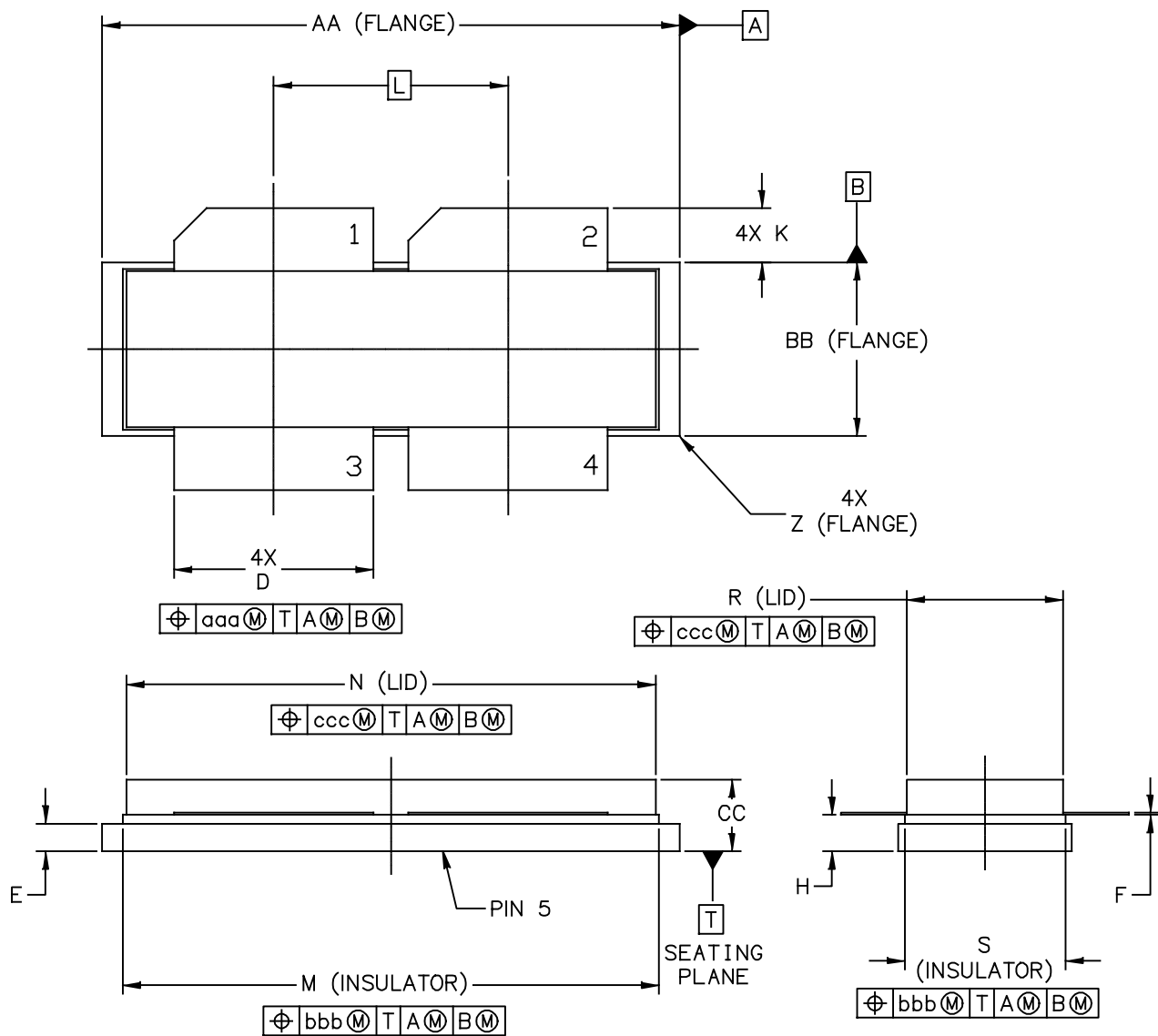


NOTES:

1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: INCH
3. DIMENSION H IS MEASURED .030 INCH (0.762 MM) AWAY FROM PACKAGE BODY.

4.  RECOMMENDED BOLT CENTER DIMENSION OF 1.52 INCH (38.61 MM) BASED ON M3 SCREW.

| INCH                                                    |           |       | MILLIMETER         |       | INCH                                 |                            |       | MILLIMETER |       |
|---------------------------------------------------------|-----------|-------|--------------------|-------|--------------------------------------|----------------------------|-------|------------|-------|
| DIM                                                     | MIN       | MAX   | MIN                | MAX   | DIM                                  | MIN                        | MAX   | MIN        | MAX   |
| AA                                                      | 1.615     | 1.625 | 41.02              | 41.28 | N                                    | 1.218                      | 1.242 | 30.94      | 31.55 |
| BB                                                      | .395      | .405  | 10.03              | 10.29 | Q                                    | .120                       | .130  | 3.05       | 3.30  |
| CC                                                      | .170      | .190  | 4.32               | 4.83  | R                                    | .355                       | .365  | 9.02       | 9.27  |
| D                                                       | .455      | .465  | 11.56              | 11.81 | S                                    | .365                       | .375  | 9.27       | 9.53  |
| E                                                       | .062      | .066  | 1.57               | 1.68  |                                      |                            |       |            |       |
| F                                                       | .004      | .007  | 0.10               | 0.18  |                                      |                            |       |            |       |
| G                                                       | 1.400 BSC |       | 35.56 BSC          |       | aaa                                  | .013                       |       | 0.33       |       |
| H                                                       | .082      | .090  | 2.08               | 2.29  | bbb                                  | .010                       |       | 0.25       |       |
| K                                                       | .117      | .137  | 2.97               | 3.48  | ccc                                  | .020                       |       | 0.51       |       |
| L                                                       | .540 BSC  |       | 13.72 BSC          |       |                                      |                            |       |            |       |
| M                                                       | 1.219     | 1.241 | 30.96              | 31.52 |                                      |                            |       |            |       |
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. |           |       | MECHANICAL OUTLINE |       |                                      | PRINT VERSION NOT TO SCALE |       |            |       |
| TITLE:<br><br>NI-1230-4H                                |           |       |                    |       | DOCUMENT NO: 98ASB16977C      REV: F |                            |       |            |       |
|                                                         |           |       |                    |       | STANDARD: NON-JEDEC                  |                            |       |            |       |
|                                                         |           |       |                    |       | 28 FEB 2013                          |                            |       |            |       |



|                                                         |                                      |                            |
|---------------------------------------------------------|--------------------------------------|----------------------------|
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. | MECHANICAL OUTLINE                   | PRINT VERSION NOT TO SCALE |
| TITLE:<br><br>NI-1230-4S                                | DOCUMENT NO: 98ARB18247C      REV: G |                            |
|                                                         | STANDARD: NON-JEDEC                  |                            |
|                                                         | 01 MAR 2013                          |                            |

NOTES:

1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M–1994.
2. CONTROLLING DIMENSION: INCH
3. DIMENSION H IS MEASURED .030 INCH (0.762 MM) AWAY FROM PACKAGE BODY

| DIM                                                     | INCHES   |       | MILLIMETERS        |       | DIM                                  | INCHES                     |       | MILLIMETERS |       |
|---------------------------------------------------------|----------|-------|--------------------|-------|--------------------------------------|----------------------------|-------|-------------|-------|
|                                                         | MIN      | MAX   | MIN                | MAX   |                                      | MIN                        | MAX   | MIN         | MAX   |
| AA                                                      | 1.265    | 1.275 | 32.13              | 32.39 | R                                    | .355                       | .365  | 9.02        | 9.27  |
| BB                                                      | .395     | .405  | 10.03              | 10.29 | S                                    | .365                       | .375  | 9.27        | 9.53  |
| CC                                                      | .170     | .190  | 4.32               | 4.83  | Z                                    | R.000                      | R.040 | R0.00       | R1.02 |
| D                                                       | .455     | .465  | 11.56              | 11.81 |                                      |                            |       |             |       |
| E                                                       | .062     | .066  | 1.57               | 1.68  | aaa                                  | .013                       |       | 0.33        |       |
| F                                                       | .004     | .007  | 0.10               | 0.18  | bbb                                  | .010                       |       | 0.25        |       |
| H                                                       | .082     | .090  | 2.08               | 2.29  | ccc                                  | .020                       |       | 0.51        |       |
| K                                                       | .117     | .137  | 2.97               | 3.48  |                                      |                            |       |             |       |
| L                                                       | .540 BSC |       | 13.72 BSC          |       |                                      |                            |       |             |       |
| M                                                       | 1.219    | 1.241 | 30.96              | 31.52 |                                      |                            |       |             |       |
| N                                                       | 1.218    | 1.242 | 30.94              | 31.55 |                                      |                            |       |             |       |
| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED. |          |       | MECHANICAL OUTLINE |       |                                      | PRINT VERSION NOT TO SCALE |       |             |       |
| TITLE:<br><br>NI-1230-4S                                |          |       |                    |       | DOCUMENT NO: 98ARB18247C      REV: G |                            |       |             |       |
|                                                         |          |       |                    |       | STANDARD: NON-JEDEC                  |                            |       |             |       |
|                                                         |          |       |                    |       | 01 MAR 2013                          |                            |       |             |       |

## PRODUCT DOCUMENTATION AND SOFTWARE

Refer to the following resources to aid your design process.

### Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

### Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

### Software

- Electromigration MTTF Calculator

For Software, do a Part Number search at <http://www.freescale.com>, and select the "Part Number" link. Go to the Software & Tools tab on the part's Product Summary page to download the respective tool.

## REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date      | Description                                                                       |
|----------|-----------|-----------------------------------------------------------------------------------|
| 0        | July 2014 | <ul style="list-style-type: none"> <li>• Initial Release of Data Sheet</li> </ul> |

### ***How to Reach Us:***

**Home Page:**  
[freescale.com](http://freescale.com)

**Web Support:**  
[freescale.com/support](http://freescale.com/support)

Information in this document is provided solely to enable system and software implementers to use Freescale products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits based on the information in this document.

Freescale reserves the right to make changes without further notice to any products herein. Freescale makes no warranty, representation, or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale data sheets and/or specifications can and do vary in different applications, and actual performance may vary over time. All operating parameters, including "typicals," must be validated for each customer application by customer's technical experts. Freescale does not convey any license under its patent rights nor the rights of others. Freescale sells products pursuant to standard terms and conditions of sale, which can be found at the following address: [freescale.com/SalesTermsandConditions](http://freescale.com/SalesTermsandConditions).

Freescale and the Freescale logo are trademarks of Freescale Semiconductor, Inc., Reg. U.S. Pat. & Tm. Off. All other product or service names are the property of their respective owners.

© 2014 Freescale Semiconductor, Inc.